

### **3V DCS LOW NOISE AMPLIFIER**

## Typical Applications

- LNA for DCS 1800/1900 Handsets
- IF or RF Buffer Amplifiers

- Driver Stage for Power Amplifiers
- Oscillator Loop Amplifiers

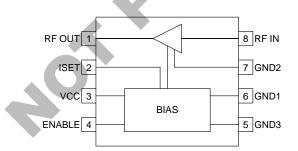
## **Product Description**

The RF2445 is a general purpose, low-cost, high-performance, low-noise amplifier designed for operation from a 2.7V to 3.6V supply with low current consumption. The device features a power-down mode with controlled attenuation, which can be used to save current while providing a controlled gain step. The device linearity (Input IP3) and current drain are set with an external resistor, allowing the designer to select the optimum performance for a given application. "Proportional to Absolute Temperature (PTAT)" biasing is used to provide consistent performance across a wide temperature range. The RF2445 is available in a small industry-standard MSOP-8 lead surface mount package, enabling compact designs which conserve board space.

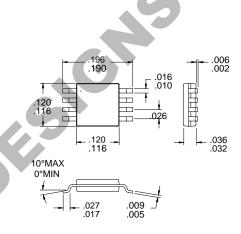
Optimum Technology Matching® Applied

☐ Si BJT ☐ GaAs HBT ☐ GaAs MESFET

✓ Si Bi-CMOS ☐ SiGe HBT ☐ Si CMOS



Functional Block Diagram



Package Style: MSOP-8

#### **Features**

- 700MHz to 2000MHz Operation
- 2.7V to 3.6V Single Supply
- -5dBm Input IP<sub>3</sub> at 5.3mA
- 19dB Gain at 1950MHz
- 2.2dB Noise Figure
- 27dB Gain Step

#### Ordering Information

RF2445 3V DCS Low Noise Amplifier
RF2445 PCBA Fully Assembled Evaluation Board

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# **RF2445**

### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Voltage	4.0	V
Supply Current	20	mA
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



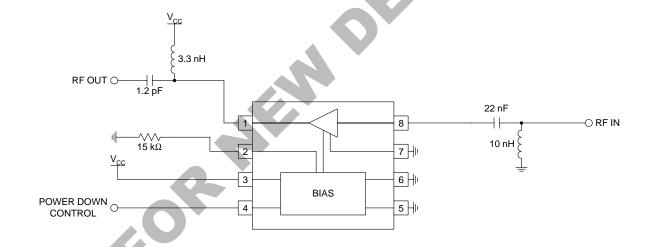
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Doromotor	Specification		l lmi4	Condition	
Parameter	Parameter Min. Typ. Max. Unit	Unit			
Overall					V <sub>CC</sub> =2.7V, T=27°C
Frequency Range		700 to 2000		MHz	
High Gain Mode					$V_{ENABLE}$ =2.7V, $R_{ISET}$ =15k $\Omega$
Gain		20.5		dB	At 1700MHz
Noise Figure		1.8		dB	
Input IP3		-6.0		dBm	
Gain		18.5		dB	At 1880MHz
Noise Figure		2.2		dB	
Input IP3		-4.0		dBm	
Input VSWR		2:1			
Output VSWR		1.5:1			
Gain		18		dB	At 2000MHz
Noise Figure		2.5		dB	At 2000 WI 12
Input IP3		-3.0		dBm	
Power-Down Mode					V <sub>ENABLE</sub> =0V
Gain		-6.0		dB	At 1700MHz
Gain		-8.0		dB	At 1880MHz
Gain		-7.0		dB	At 2000MHz
Power Supply					
Power Supply Range (VCC)	2.7	3.0	3.6	V	
Current Drain (ICC)		5.3	7.0	mA	$V_{ENABLE}$ =2.7V, $R_{ISET}$ =15kΩ (High Gain Mode)
Current into ENABLE			1	μа	V <sub>ENABLE</sub> =2.7V
Current Drain (ICC)			1	μа	V <sub>ENABLE</sub> =0V (Power-Down Mode)

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Pin	Function	Description	Interface Schematic
1	RF OUT	RF output pin. The output impedance of this pin is internally matched to $50\Omega$ using feedback. Bias for the LNA is provided through this pin, hence it should be connected to VCC through an inductor.	
2	ISET	This pin sets the current for the device. A resistor to ground of $15k\Omega$ provides a current of 5.3mA.	
3	VCC	Power supply for the bias circuits.	
4	POWER DOWN CONTROL	Power down control. This is a CMOS input. When this pin is CMOS "high" the device is enabled. When the level is CMOS "low" the device is shut off and a controlled attenuator is turned on.	
5	GND3	Ground connection for the LNA. Keep traces physically short and connect immediately to ground plane for best performance.	6
6	GND1	Same as pin 5.	
7	GND2	Ground connection for the bias circuits.	
8	RF IN	RF input pin. This pin is not internally DC blocked and requires an external blocking capacitor. The input impedance of this pin is internally matched to $50\Omega$ using feedback.	

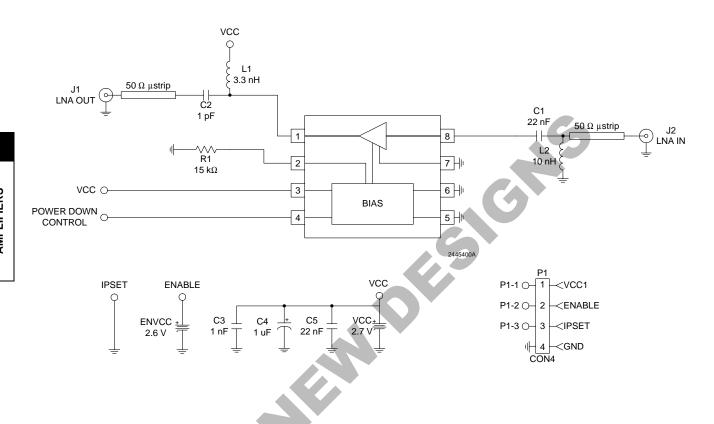
# **Application Schematic**



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# **Evaluation Board Schematic**

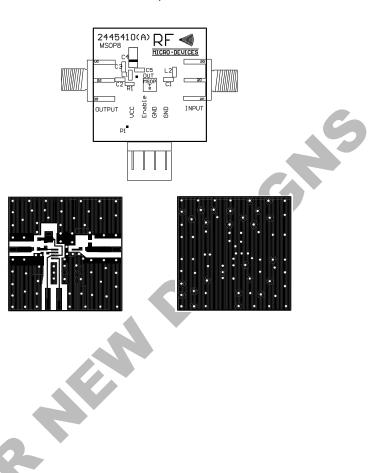
(Download Bill of Materials from www.rfmd.com.)



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# Evaluation Board Layout Board Size 1.0" x 1.0"

Board Thickness 0.031"; Board Material FR-4



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